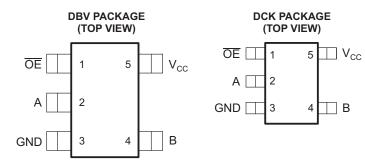


FEATURES

- 5-Ω Switch Connection Between Two Ports
- TTL-Compatible Control Input Levels
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22

 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)



See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The SN74CBTD1G125 features a single high-speed line switch. The switch is disabled when the output-enable $\overline{(OE)}$ input is high. A diode to V_{CC} is integrated on the chip to allow for level shifting from 5-V signals at the device inputs to 3.3-V signals at the device outputs.

ORDERING INFORMATION

T _A	PACK	AGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽²⁾		
		Reel of 3000	SN74CBTD1G125DBVR	DOF		
40°C to 95°C	SOT (SOT-23) – DBV	Reel of 250	SN74CBTD1G125DBVT	P25_		
–40°C to 85°C		Reel of 3000 SN74CBTD1G125DCKR		DM		
	SOT (SC-70) – DCK	Reel of 250	SN74CBTD1G125DCKT	PM_		

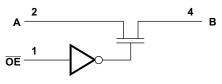
(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) The actual top-side marking has one additional character that designates the assembly/test site.

FUNCTION TABLE

	FUNCTION
L	A port = B port
Н	Disconnect

LOGIC DIAGRAM (POSITIVE LOGIC)





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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			Ν	/IN M/	X	UNIT
V_{CC}	Supply voltage range		-	0.5	7	V
VI	Input voltage range ⁽²⁾		-	0.5	7	V
	Continuous channel current			1	28	mA
I _{IK}	Input clamp current	V _{I/O} < 0		-	50	mA
0	Deckers thermal impedance (3)	DBV package		2	06	°C/W
θ_{JA}	Package thermal impedance ⁽³⁾	DCK package		2	52	°C/W
T _{stg}	Storage temperature range		-	-65 1	50	°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings (1)only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed. (2)

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

		MIN	MAX	UNIT
V_{CC}	Supply voltage	4.5	5.5	V
V_{IH}	High-level control input voltage ⁽²⁾	2		V
V_{IL}	Low-level control input voltage		0.8	V
T _A	Operating free-air temperature	-40	85	°C

(1) All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

In applications with fast edge rates, multiple outputs switching, and operating at high frequencies, the output may have little or no (2) level-shifting effect.

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

Р	ARAMETER		TEST COND	ITIONS	MIN TYP ⁽¹⁾	UNIT	
V _{IK}		V _{CC} = 4.5 V,	I _I = -18 mA			-1.2	V
V _{OH}		See Figure 2					
I _I		$V_{CC} = 5.5 V,$	$V_I = 5.5 V \text{ or GND}$			±1	μA
I _{CC}		$V_{CC} = 5.5 V,$	I _O = 0,	$V_1 = V_{CC}$ or GND		1.5	mA
$\Delta I_{CC}^{(2)}$	Control input	V _{CC} = 5.5 V,	One input at 3.4 V,	Other inputs at V_{CC} or GND		2.5	mA
Ci	Control input	$V_{I} = 3 V \text{ or } 0$			2		pF
C _{io(OFF)}		$V_{O} = 3 V \text{ or } 0,$	$\overline{OE} = V_{CC}$		3.5		pF
			$V_1 = 0$	I _I = 64 mA	5	7	
$r_{on}^{(3)}$		$V_{CC} = 4.5 V$	V _I = 0	I _I = 30 mA	5	7	Ω
			V _I = 2.4 V,	l _l = 15 mA	35	50	

(1)

(2)

All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$. This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND. Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. On-state resistance is (3) determined by the lower voltage of the two (A or B) terminals.

Switching Characteristics

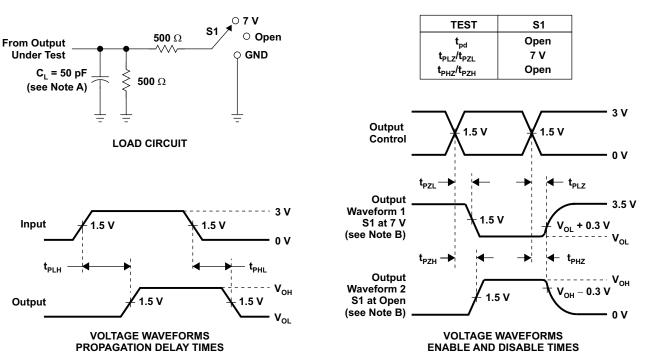
over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	МАХ	UNIT
t _{pd} ⁽¹⁾	A or B	B or A		0.25	ns
t _{en}	ŌE	A or B	2	5.9	ns
t _{dis}	ŌĒ	A or B	1	4.7	ns

(1) The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

SN74CBTD1G125 SINGLE FET BUS SWITCH WITH LEVEL SHIFTING

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PARAMETER MEASUREMENT INFORMATION

TEXAS

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NOTES: A. C₁ includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_Q = 50 Ω, t_f ≤ 2.5 ns. t_f ≤ 2.5 ns.

D. The outputs are measured one at a time with one transition per measurement.

E. t_{PLZ} and t_{PHZ} are the same as $t_{\mathsf{dis}}.$

F. t_{PZL} and t_{PZH} are the same as t_{en} .

G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS

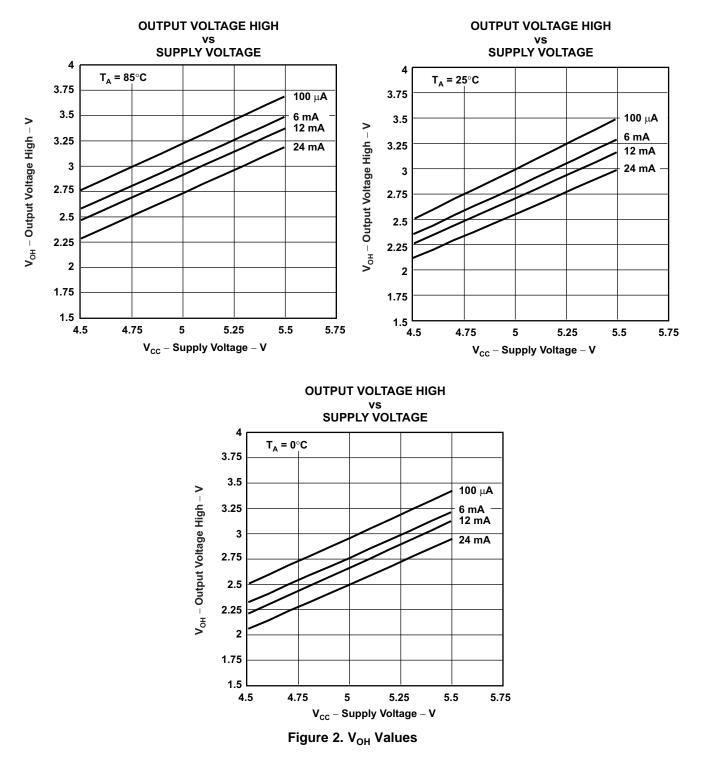
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TRUMENTS





PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
74CBTD1G125DCKRG4	NRND	SC70	DCK	5	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	(PMJ, PMR)	
SN74CBTD1G125DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	(P25J, P25R)	Samples
SN74CBTD1G125DBVT	NRND	SOT-23	DBV	5	250	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	(P25J, P25R)	
SN74CBTD1G125DCKR	NRND	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	(PMJ, PMR)	
SN74CBTD1G125DCKT	NRND	SC70	DCK	5	250	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	(PMJ, PMR)	

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



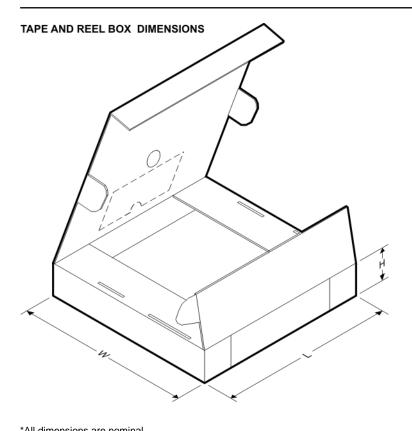
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CBTD1G125DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
SN74CBTD1G125DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74CBTD1G125DBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
SN74CBTD1G125DBVT	SOT-23	DBV	5	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74CBTD1G125DCKR	SC70	DCK	5	3000	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74CBTD1G125DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74CBTD1G125DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74CBTD1G125DCKT	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3

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PACKAGE MATERIALS INFORMATION

1-Aug-2019



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CBTD1G125DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74CBTD1G125DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74CBTD1G125DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74CBTD1G125DBVT	SOT-23	DBV	5	250	202.0	201.0	28.0
SN74CBTD1G125DCKR	SC70	DCK	5	3000	202.0	201.0	28.0
SN74CBTD1G125DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74CBTD1G125DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74CBTD1G125DCKT	SC70	DCK	5	250	202.0	201.0	28.0

DBV0005A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



DBV0005A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DBV0005A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



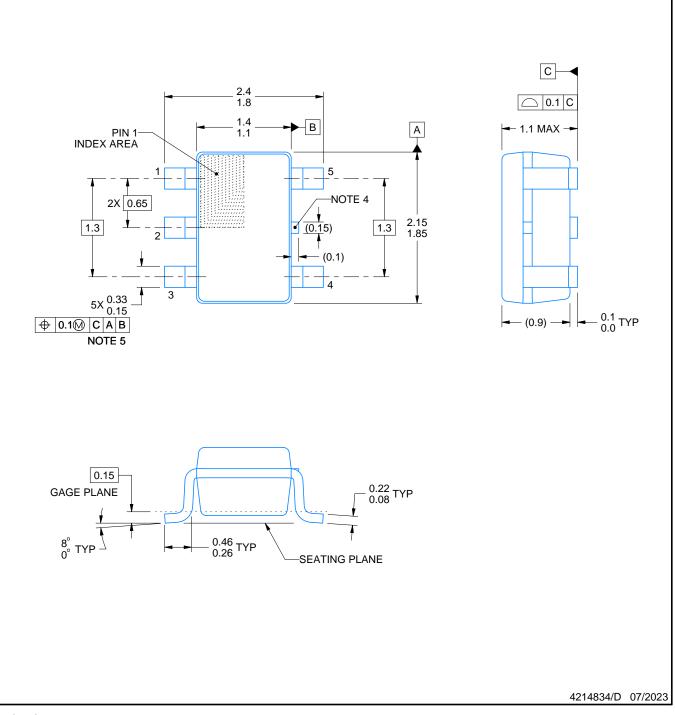
DCK0005A



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.5. Lead width does not comply with JEDEC.



DCK0005A

EXAMPLE BOARD LAYOUT

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DCK0005A

EXAMPLE STENCIL DESIGN

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



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